

Voltage Detectors With Delay Circuit Built-In

■ General Description

The LN61F is a micro-power voltage detector supervising the power supply voltage level for microprocessors or digital systems, which is extremely accurate with minimal temperature drift.

It provides internally fixed threshold levels with 0.1V per step ranging from 1.5V to 5V, which covers most digital applications. It features low supply current. Both CMOS and N-channel open drain output configurations are available. Since the delay circuit is built-in, peripherals are unnecessary and high density mounting is possible.

■ Features

- Highly Accurate $\pm 2\%$
- Low Power Consumption lower than 1.5 μ A
- Detect Voltage Range 1.5V ~ 5.0V in 0.1V increments
- Operating Voltage Range 0.7V ~ 7.0V
- Detect Voltage Temperature Characteristics: \pm

100ppm/ $^{\circ}$ C (TYP.)

- Built-In Delay Circuit

The option items include: 50ms, 100ms, 200ms and 400ms

- Output Configuration: N-channel open drain or CMOS

■ Applications

- Microprocessor reset circuitry
- Memory battery back-up circuits
- Power-on reset circuits
- Power failure detection
- System battery life and charge voltage monitors
- Delay circuitry

■ Package

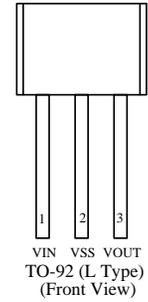
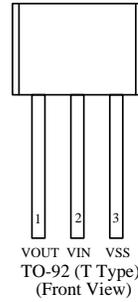
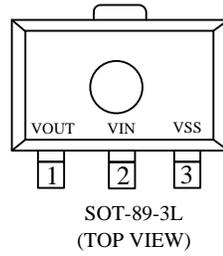
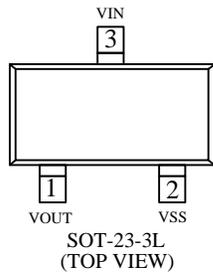
- SOT-23-3L
- SOT-89-3L
- TO-92

■ Ordering Information

LN61F ①②③④⑤⑥⑦

Designator	Description	Symbol	Description
①	Output Configuration	C	CMOS output
		N	N-ch open drain output
②③	Detect Voltage	15~50	e.g. 2.5V \rightarrow ②2, ③5
			e.g. 3.8V \rightarrow ②3, ③8
④	Output Delay	1	70ms-150ms
		2	330ms-500ms
		4	150ms-270ms
		5	30ms-80ms
⑤	Detect Accuracy	2	Within $\pm 2.0\%$
⑥	Package	M	SOT-23
		P	SOT-89
		T	TO-92 (Standard)
		L	TO-92 (Custom pin configuration)
⑦	Device Orientation	R	Embossed tape, standard feed
		L	Embossed tape, reverse feed
		H	Paper type (TO-92)
		B	Bag (TO-92)

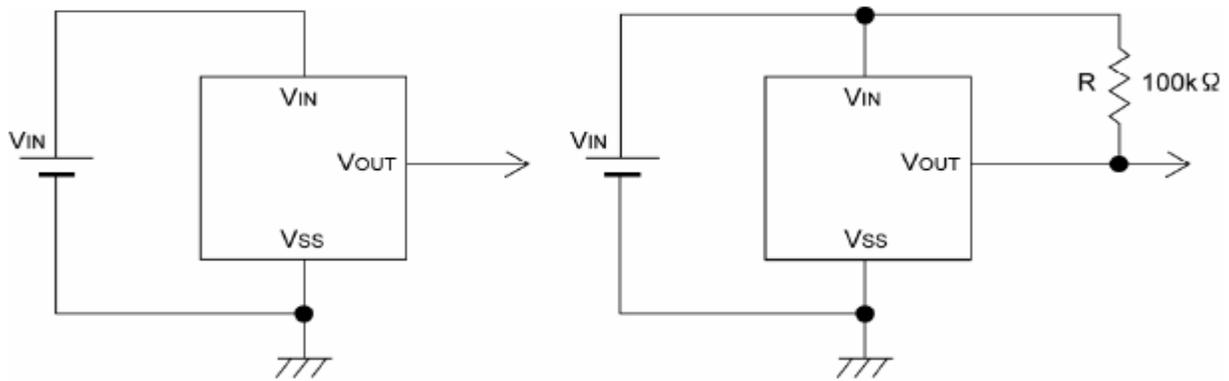
Pin Configurations



Pin Assignment

Pin Number				Pin Name	Function
SOT-23-3L	SOT-89-3L	TO-92(T)	TO-92(L)		
3	2	2	1	VIN	Supply Voltage Input
2	3	3	2	VSS	Ground
1	1	1	3	VOUT	Output

Typical Application Circuit

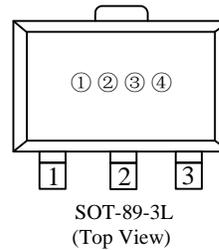
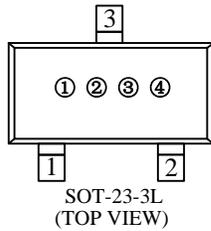


CMOS output

N-channel open drain output

■ Marking Rule

- SOT-23-3L, SOT-89-3L



- ① Represents integer of detect voltage and output configuration

CMOS output (LN61FC series)

Mark	Configuration	Voltage(V)
A	CMOS	0.X
B	CMOS	1.X
C	CMOS	2.X
D	CMOS	3.X
E	CMOS	4.X
F	CMOS	5.X

N-channel open drain (LN61FN series)

Mark	Configuration	Voltage(V)
K	N-ch	0.X
L	N-ch	1.X
M	N-ch	2.X
N	N-ch	3.X
P	N-ch	4.X
R	N-ch	5.X

- ② Represents decimal number of detect voltage

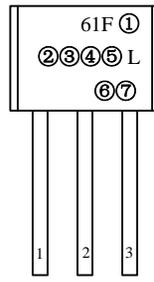
Mark	Voltage(V)	Mark	Voltage(V)
0	X.0	5	X.5
1	X.1	6	X.6
2	X.2	7	X.7
3	X.3	8	X.8
4	X.4	9	X.9

- ③ Represents delay time

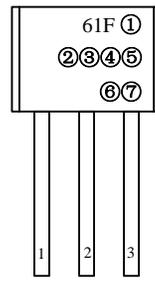
Mark	Delay Time
5	70ms-150ms
6	330ms-500ms
8	150ms-270ms
7	30ms-80ms

- ④ Represents assembly lot number (Based on internal standards)

● TO-92



TO-92 (L Type)
(Front View)



TO-92 (T Type)
(Front View)

① Represents the output configuration

Designator	Output Configuration
C	CMOS
T	N-ch open drain

④ Represents delay time

Mark	Delay Time
1	50ms ~ 200ms
4	80ms ~ 400ms
5	1ms ~ 50ms

⑥ Represents a least significant digit of the produced year

Designator	Produced Year
8	2008
9	2009

⑦ Represents production lot number

0~9, A~Z repeated (G, I, J, O, Q, W excepted)

② ③ Represents the detect voltage

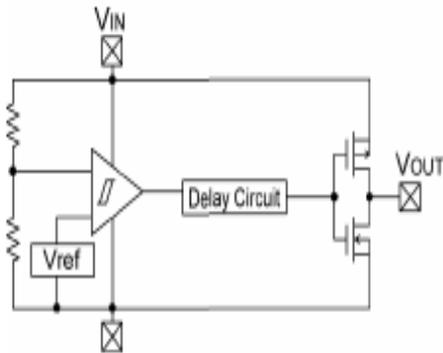
Designator		Detect Voltage (V)
②	③	
3	3	3.3
5	0	5.0

⑤ represents the detect voltage accuracy

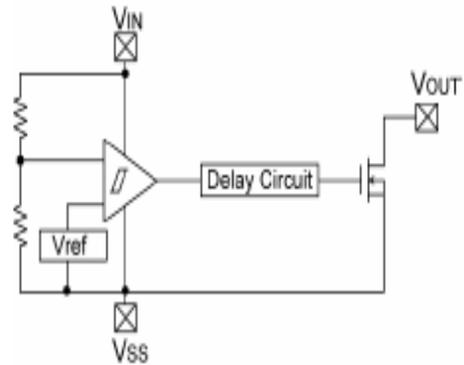
Designator	Output Accuracy
1	Within $\pm 1\%$
2	Within $\pm 2\%$

■ Function Block Diagram

(1) CMOS output



(2) N-channel open drain output



■ Absolute Maximum Ratings

Parameter	Symbol	Maximum Rating	Unit
Input Supply Voltage	V_{IN}	12	V
Output Current	I_{OUT}	30	mA
Output Voltage	CMOS	$V_{SS} - 0.3 \sim V_{IN} + 0.3$	V
	N-ch open drain	$V_{SS} - 0.3 \sim 9$	
Power Dissipation	SOT-23	150	mW
	SOT-89	500	
	TO-92	300	
Operating Temperature Range	T_{opr}	$-30 \sim +85$	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	$-40 \sim +125$	$^{\circ}\text{C}$

■ Electrical Characteristics

Ta=25°C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Detect Voltage	VDF		VDF(T) x 0.98	VDF(T)	VDF(T) x 1.02	V
Hysteresis Range	VHYS		VDF x 0.02	VDF x 0.05	VDF x 0.08	V
Supply Current	ISS	VIN = 1.5V		1.2	2.0	μA
		VIN = 2.0V		1.3	2.5	
		VIN = 3.0V		1.3	3.0	
		VIN = 4.0V		1.4	3.5	
		VIN = 5.0V		1.6	4	
Operating Voltage	VIN	VDF= 1.6V to 6.0V	0.7		7	V
Output Current	IOUT	N-ch VDF =0.5V	VIN = 1.5V		2	mA
			VIN = 2.0V		7	
			VIN = 3.0V		10	
			VIN = 4.0V		11	
			VIN = 5.0V		13	
		CMOS, P-ch VDF=2.1V VIN = 8.0V		-10		
Detect Voltage Temperature Characteristics	Δ VDF Δ Topr· VDF			± 100		ppm/°C
Transient Delay Time (VDR → VOUT inversion)	TDLY	LN61F***1***	70		150	ms
		LN61F***2***	330		500	ms
		LN61F***4***	150		270	ms
		LN61F***5***	30		80	ms

VDF (T): Setting detect voltage value

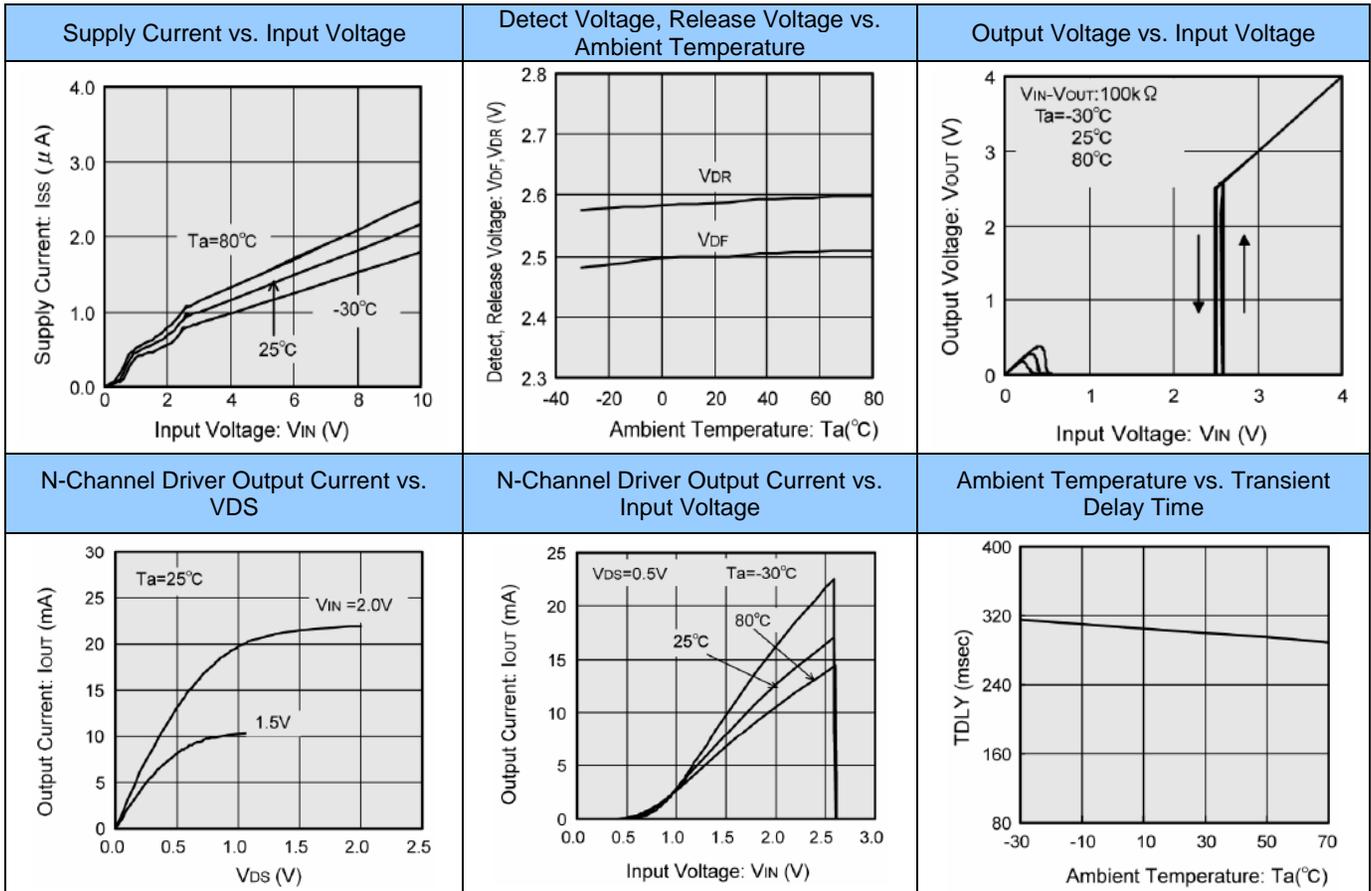
Release Voltage: VDR = VDF + VHYS

* Transient Delay Time: 1ms to 50ms & 80ms to 400ms versions are also available.

Note: The power consumption during power-start to output being stable (release operation) is 2μA greater than it is after that period (completion of release operation) because of delay circuit through current.

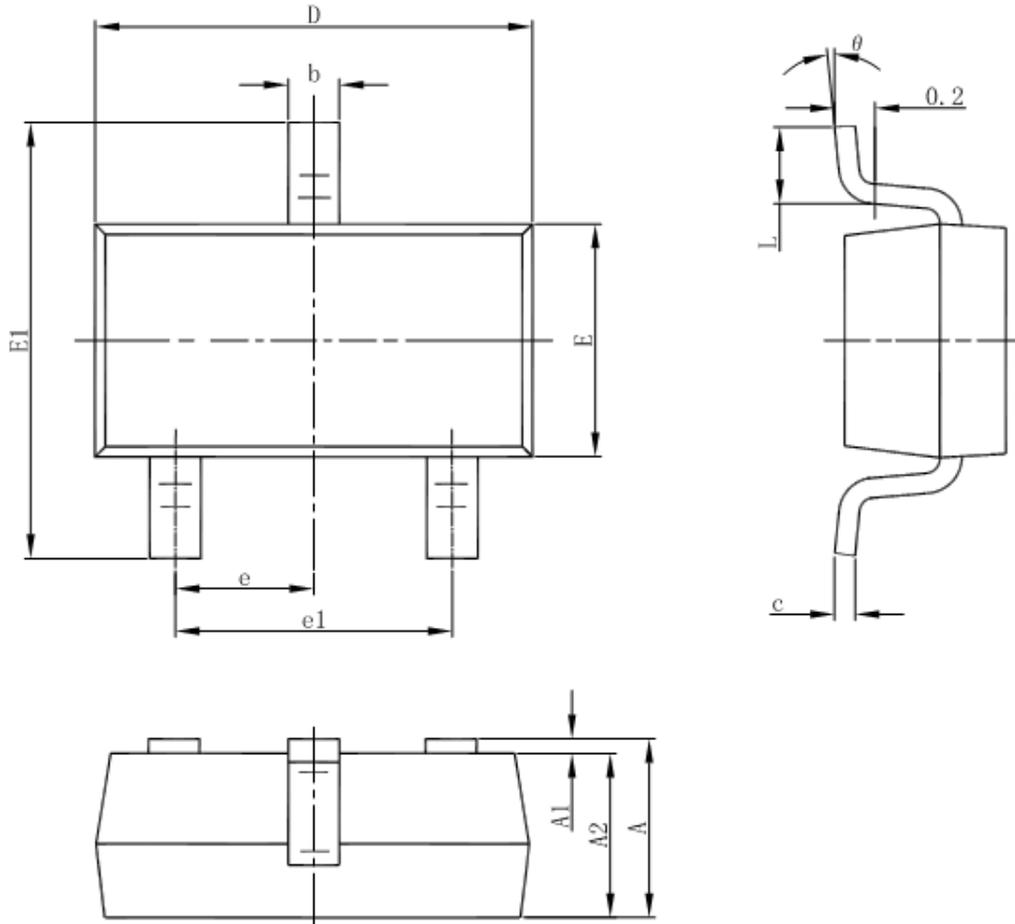
■ Typical Performance Characteristics

Product for Test: VDF=2.5V



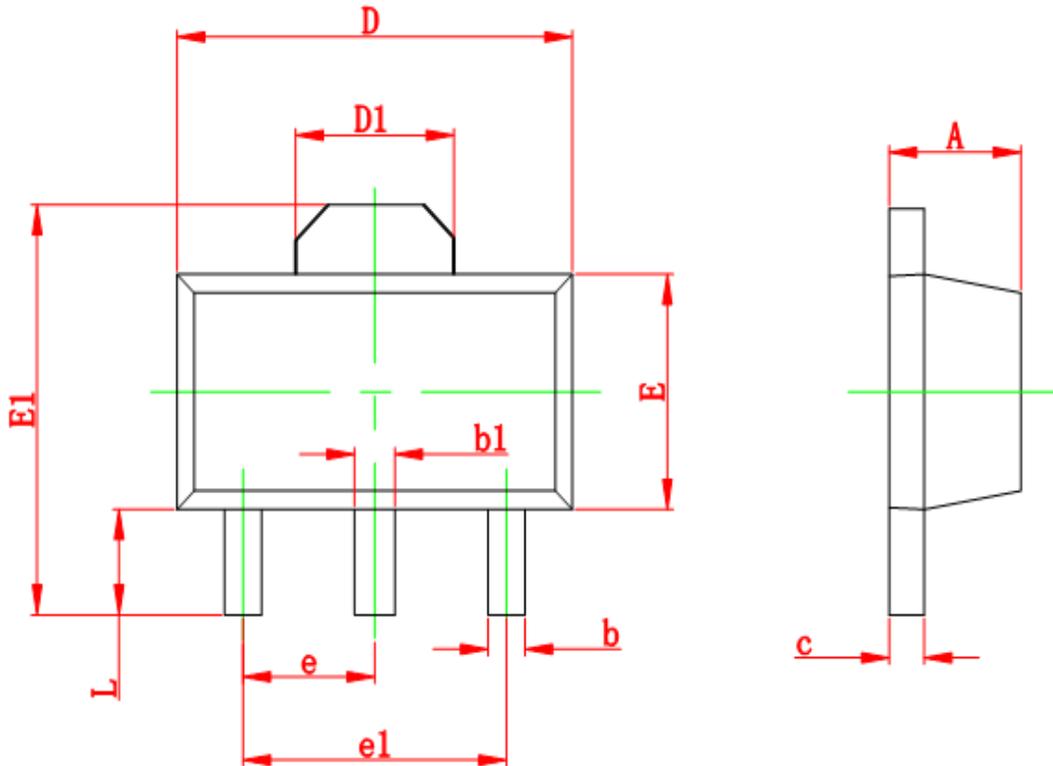
■ Package Information

- SOT-23-3L



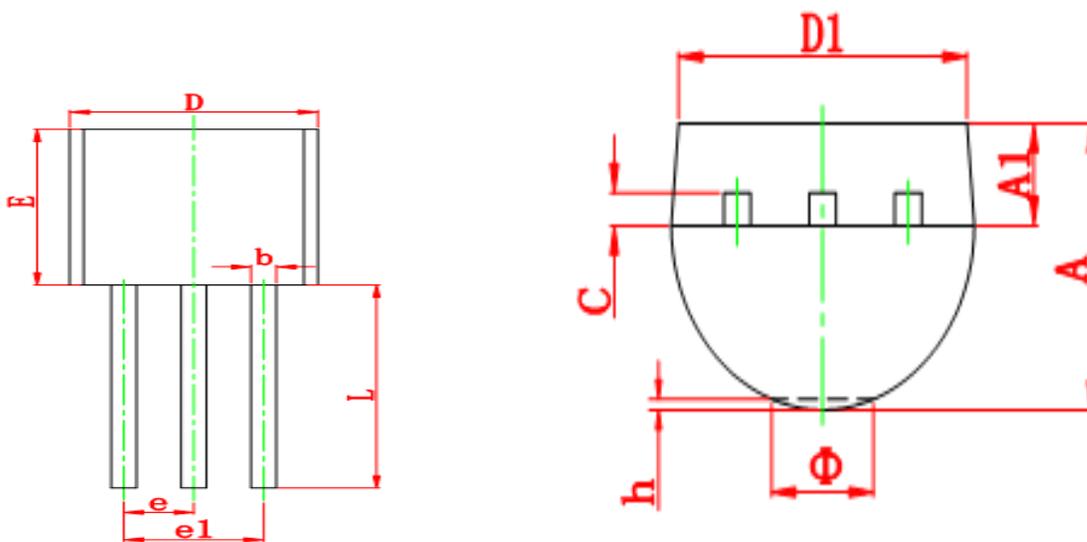
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

- SOT-89-3L



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.197
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF		0.061 REF	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP		0.060 TYP	
e1	3.000 TYP		0.118 TYP	
L	0.900	1.200	0.035	0.047

- T0-92



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.400	4.700	0.173	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015